

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1	(non-electrically adj2 programmable adj2 (three-dimensional) adj2 memory)	US-PGPU B; USPAT
2	BRS	L2	1	(non-electrically near4 programmable near4 (three adj2 dimensional) near4 memory)	US-PGPU B; USPAT
3	BRS	L3	4	((non adj2 electrically) near4 programmable near4 (three adj2 dimensional) near4 memory)	US-PGPU B; USPAT
4	IS&R	L4	1009	(257/390).CCLS.	US-PGPU B; USPAT
5	IS&R	L5	1390	(257/401).CCLS.	US-PGPU B; USPAT

	Type	L #	Hits	Search Text	DBs
6	BRS	L6	3	((non adj2 electrically) near4 programmable near4 (three adj2 dimensional) near4 memory)	USOC R; FPRS; EPO; JPO; DERW ENT; IBM_T DB
7	BRS	L7	4	((non adj2 electrically) near6 programmable near6 (three adj2 dimensional) near6 memory)	US- PGPU B; USPA T
8	BRS	L8	4	((non adj2 electrically) near10 programmable near10 (three adj2 dimensional) near10 memory)	US- PGPU B; USPA T